Astro-E2

X-ray Imaging Spectrometer Status, Performance and Calibration

Astro-E2 Users' Group 14 February 2005

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XIS Team Members (Partial list)

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The XIS at a Glance



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- Four telescope + CCD camera units
- Effective area:
 - 1500 cm² @ 1 keV (~2*x* Chandra/ACIS) 600 cm² @ 6 keV (~ XMM/EMOS) 60 cm² @ 0.25 keV
- Field of view:
 - 18 x 18 arcmin (~*Chandra*/*ACIS-I*)
- Spectral Resolution: Silicon-limited E> 0.7 keV (R~2-10%) ~60 eV @ 0.25 keV (x2 < CXO/XMM)
- Team:
 - ISAS (Digital electronics, integration)Osaka (Door, filter, ground calibration)Kyoto (Ground calibration)MIT (CCD, TEC, analog electronics, ground calibration)

Astro-E2 Instrument Configuration



Astro-E2 XIS Flight Hardware

Components:

- 4 X-ray photon-counting CCD sensors, Peltier-cooled
- 2 low-noise front-end electronics
- sets with thermal controllers 14 February 2005

Key Characteristics:

- Low noise (1-2 e⁻ RMS)
- Deep depletion (65 µm)
- Charge injection capability
- Front- & back-illumination
- CCDs fabricated at MIT/Lincoln
- CCD heritage: Chandra, ASCA





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XIS Effective Area Comparison: 1 BI Sensor vs 1 FI Sensor



XIS Spectral Resolution: FI & BI CCDs

See also LaMarr et al., poster 5501-51



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XIS Spectral Resolution Comparison: BI vs FI

Simulated Spectra of SNR E0102 -72.3



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Charge Injection: Motivation

- XRS has 30-36 month life before cryogen is exhausted
- XIS CCD performance late in Astro-E2 mission is thus especially important
- Some radiation damage to XIS is inevitable in the Astro-E2 orbit (600 km, 31 deg)
- Charge injection capability mitigates radiation damage two ways:
 - * Improves charge transfer efficiency after radiation
 - * Allows better ground calibration and correction for damage effects

XIS Spectral Resolution after Irradiaton without Charge Injection



XIS Spectral Resolution after Irradiaton with Charge Injection



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Ground Calibration Summary

- MIT: QE & Spectral Resolution vs position, 0.3 10 keV
- Osaka: QE & Spectral Resolution, 0.3-1.8 keV
- Kyoto: QE & Spectral Resolution, 1.4-12 keV
- Ehime: Filter Transmission 0.3-5 keV; optical
- Issues:
 - Low-energy (E < 0.5 keV) QE of BI sensor reference detector calibration, pileup(MIT) source stability (Osaka)
 - * CTI correction in pipeline & response functions

Original XIS Flight Calibration Plan

per H. Matsumoto et al.; revisions pending

Target	Mode	Date	Exp	Pri.	Purpose/Remarks
		(MOL)	(ks)		
Vega	5x5	1	10	1	OBF Check
E0102-72	5x5	1	10	1	low-E gain, res., QE
	P-sum	1	20	1	CXO reference spectrum
	Burst	1	10	3?	
Cas-A	5x5	6	1.2	1	CTE/gain check
	P-sum	6	1.2	1	(Pri.2: 4 corners @3 ksec)
	5x5	6	12	2	
	P-sum	6	12	2	
E0102-72	5x5	6	20	1	low-E CTE, gain, QE
	P-sum	6	20	1	(Priority 2: 4 corners @,50 ksec)
	5x5	6	200	2	
	P-sum	6	200	2	
Eta Carina	5x5	1-6	20*	1	low-E BI QE, gain (N line)
Cygnus Loop	5x5	1-6	10*	1	low-E BI QE, gain (C line)

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*Parasitic on science observations

XIS Status Summary

- XIS hardware is integrated on spacecraft and ready for launch.
- All planned ground calibration measurements completed; analysis is in progress and several issues remain open.
- Calibration products in development; CTI correction remains to be implemented.

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We can't wait!

XIS Charge Injection Structure

See posters 5501-49 (Prigozhin et al.) & 5501-51(LaMarr et al.)





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"Fill & Spill" Injection

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XIS Charge Injection Structure

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•An input register is added:

*Location is "row 1025"

*Input diode (ID) & input gate (IG) at "column 0" *Can be clocked to place charge above any/all CCD columns.

•2 extra signals required:

*ID timing determines columns injected

*IG level controls injected charge quantity

*Existing serial clocks((3) transfer charge in IR

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"Fill & Spill" Sequence

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Charge Injection to Improve Charge Transfer

Charge moves right during injection

Input Register ID/IG Charge moves down during readout Ð.

• Charge injection is programmable.

"Grid" program reduces charge transfer losses due to radiation damage:
*Charge is injected in each column of every 54th row.
*Injected charge (temporarily) fills radiation-induced traps.
*Filled traps will not degrade charge transfer inefficiency.
*Result is better spectral resolution.

Rows filled by charge injection

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